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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/505,282	08/20/2004	Mikio Ikenishi	330-281	5541
23117 NIXON & VAN	7590 11/12/200 NDERHYE. PC	EXAMINER		
901 NORTH G	LEBE ROAD, 11TH F	FALASCO, LOUIS V		
AKLINGTON,	ARLINGTON, VA 22203		ART UNIT	PAPER NUMBER
			1794	
			MAIL DATE	DELIVERY MODE
			11/12/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)
	10/505,282	IKENISHI ET AL.
Office Action Summary	Examiner	Art Unit
	LOUIS FALASCO	1794
The MAILING DATE of this communication a Period for Reply	ppears on the cover sheet with the	correspondence address
A SHORTENED STATUTORY PERIOD FOR REP WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR of after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory perior. - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICATIO 1.136(a). In no event, however, may a reply be tind will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDONE	N. mely filed the mailing date of this communication. ED (35 U.S.C. § 133).
Status		
1) ☐ Responsive to communication(s) filed on 19 2a) ☐ This action is FINAL . 2b) ☐ Th 3) ☐ Since this application is in condition for allow closed in accordance with the practice under	is action is non-final. ance except for formal matters, pr	
Disposition of Claims		
4) ☐ Claim(s) 1-19 is/are pending in the application 4a) Of the above claim(s) 4-17 is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-3,18,19 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and. Application Papers 9) ☐ The specification is objected to by the Examination of the company of the specification is objected to by the Examination of the company of the specification is objected to by the Examination of the company	wn from consideration. /or election requirement. ner.	
10) The drawing(s) filed on is/are: a) according a depth and	e drawing(s) be held in abeyance. Se ection is required if the drawing(s) is ob	e 37 CFR 1.85(a). ojected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority docume 2. ☐ Certified copies of the priority docume 3. ☐ Copies of the certified copies of the priority application from the International Bure * See the attached detailed Office action for a list	nts have been received. nts have been received in Applicat iority documents have been receiv au (PCT Rule 17.2(a)).	ion No ed in this National Stage
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal I 6) Other:	ate

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DETAILED ACTION

Papers Received

- This application is acknowledged as a Request for Continuing Examination (RCE).
- 2. The Amendment filed 8/19/08 is acknowledged.
- 3. The Terminal Disclaimer filed 7/6/07 is acknowledged and approved.

Claims

- 4. The claims in this application are 1 to 19.
 - Claims 4 to 17 have been withdrawn as drawn to the previously non-elected invention Species.
 - Claims 1 to 3, 18 and 19 <u>are under consideration</u> drawn to the elected Species.

Rejections

Statutory Basis

6. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

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Rejections withdrawn

2. The **Double Patenting** rejections made in the previous Office <u>have been</u> withdrawn in response to receipt and acceptance of the 7/6/07 **Terminal Disclaimer**.

3. The rejections under 35 U.S.C. 103(a) over **Nakashima et al** (US 6387510) and **Miyamoto** (US 6395634) taken in view of **Goto et al** (US 6426311) <u>have been</u> withdrawn in response to applicants amendments to the claims.

New Rejections

4. Claims 1 to 3, 18 and 19 are rejected under 35 U.S.C. 103(a) as obvious over

Nakashima et al (US 2002-0010066) and Miyamoto (US 6395634) taken with Takei et

al (JA 2002-201040 – translation attached).

Nakashima et al teaches the glass substrate for information recording medium with components including SiO₂, Al₂O₃, BaO, Na₂O, K₂O and ZrO₂ (Nakashima et al at ¶[0007], [0019]). Nakashima et al teaches the composition - showing no Li₂O in the glass as evident in Nakashima et al Table 1, ¶[0059], Examples 1-12¹. In Nakashima et al the substrate has a *glass transition temperature* (*Tg*) 600°C or more (Nakashima et al at ¶[0013-15], [0017], [0023], [0039]). Nakashima et al does not address any *hydrosilicofluoric* acid etch rate for the glass substrate. However Miyamoto teaches the instant *hydrosilicofluoric* acid etch rate claimed at ' . . . 0.1 μm/minute or less with *hydrosilicofluoric* acid held at 45°C and a concentration measured at 1.72% by weight . .

.' (**Miyamoto** col. 7 lns 4-34, conditions at col. 14 lns 50-55) and **Miyamoto** teaches a *hydrosilicofluoric* acid etch rate through optimal balancing glass components with (hydrosilicofluoric acid etch reacting opposing and eluding components, SiO₂ and Al₂O₃ - **Miyamoto** col. 18 lns 50-57)².

It would have been *prima facie* obvious to one having ordinary skill in the art to adopt the **Miyamoto** etch rate in **Nakashima et al** to achieve improvements in a recording substrate surface **Miyamoto** col. 6 lns 62-64, col. 7 lns 16-17, col. 8 lns 21-24. Furthermore **Takei et al** shows balancing the glass composition avoiding any Li₂O content (**Takei et al** [0008]), for a high density glass recording magnetic media substrate with improved etched surface smoothness (**Takei et al** ¶[0005], [0012], [0019], [0029], [0031]).

As regard components in claims 2, 3, 18 and 19: see Nakashima et al ¶[0017], [0019] and components in Table 1 examples 8 and 18-21 ¶[0059] and components taught by Takei et al examples 2-5 at ¶[0027].

Other reference

Kurachi et al (JA 2002-160943 – translation attached) is cited but not applied as further teaching characteristic *hydrosilicofluoric* acid etch rate for glass substrate see (¶[0025-27], [0042-45], also compositions of examples 6 and 7 ¶[0078] note).

 $^{^{1}}$ More over eliminating of a component, as $Li_{2}O$, along with the component's function has long been held insufficient to render claims patentable - MPEP 2144.04

² Claiming an inherent characteristic does not necessarily render a claim patentable MPEP 2112.

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Answer to Arguments

5. Applicant's arguments with respect to the claims under consideration filed 7/6/07

have been fully considered but they are considered moot in view of the new grounds of

rejection.

Conclusion

6. The claims under consideration are 1 to 3, 18 and 19.

No claim has been allowed.

Inquires

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Louis Falasco, whose telephone number is (571)272-

1507. The examiner can normally be reached on M-F 10:30 - 7:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Carol D. Chaney, can be reached at (571)272-1284. The fax phone number

for the organization where this application or proceeding is assigned is (571)273-8300.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published

applications may be obtained from either Private PAIR or Public PAIR. Status

information for unpublished applications is available through Private PAIR only. For

more information about the PAIR system, see http://pair-direct.uspto.gov. Should you

have questions on access to the Private PAIR system, contact the Electronic Business

Center (EBC) at 866-217-9197 (toll-free).

LF 10/08

/Louis Falasco/

Examiner, Art Unit 1794

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/Carol Chaney/ Supervisory Patent Examiner, Art Unit 1794